Enhanced Spin–Orbit Coupled Photoluminescence of Perovskite CsPbBr₃ Quantum Dots by Piezo-Phototronic Effect

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ABSTRACT: Piezo-phototronic effect is a fundamental effect of semiconductors lacking of central symmetry with geometries from one-dimensional (1D) nanowire to 3D bulk. Here, we present that the piezo-phototronic effect can even tune a spin–orbit coupled photoluminescence (PL) based on all-inorganic perovskite CsPbBr₃ quantum dots (QDs). Although the cubic structure of CsPbBr₃ QDs is nonpiezoelectric, a cooling treatment can change it to an orthorhombic structure, which is proven to possess a piezoelectric property. The spin–orbit coupled PL intensity is demonstrated to be dependent on the polarization of the excited light. Because of the manipulation of the spin-split energy levels via the piezo-phototronic effect, the spin–orbit coupled PL intensities under a −0.9% compressive strain for linearly and circularly polarized light excitations can be enhanced by 136% and 146%, respectively. These findings reveal fundamental understandings of the spin–orbit coupled PL dynamics and demonstrate promising optoelectronic applications of the piezo-phototronic effect in these QDs.

KEYWORDS: piezo-phototronic effect, piezo-potential, spin–orbit coupling, photoluminescence, all-inorganic perovskites

Halide perovskites have attracted enormous attention due to their excellent optoelectronic properties for applications in solar cells, photodetectors, light-emitting diodes, and lasers. Rapid development in bulk perovskite materials has also inspired extensive researches for perovskite nanostructures. Among them, the all-inorganic colloidal cesium lead halide perovskites (CsPbX₃, X = Cl, Br, I) quantum dots (QDs) featuring large quantum-size effect have drawn growing interest for their outstanding optical characteristics, which make CsPbX₃ QDs better candidates for new-generation light sources, display techniques, and bioluminescence labeling. The discovery and study of the piezoelectric property of inorganic CsPbX₃ QDs are of great significance for high-performance optoelectronic devices. It has been demonstrated that organic–inorganic lead halide perovskites have revealed strong piezoelectricity due to the alignment of organic molecular (such as methylammonium (MA)) dipoles. However, in all-inorganic CsPbX₃ QDs the piezoelectric property has been rarely reported. The reason lies in that the CsPbX₃ QDs are usually cubic structure at room temperature, which is a steady structure and hence insensitive to mechanical stimuli.

Piezotronic and piezo-phototronic effects are two born features of semiconductors that lack center symmetry, which have been widely utilized in materials such as third-generation semiconductors, transition-metal dichalcogenides, and organic–inorganic lead halide perovskites to enhance the performances of electronic and optoelectronic devices. The piezo-phototronic effect regards to the regulation of generation, separation, transfer, and/or recombination of electron–hole pairs at semiconductor interfaces by employing strain-induced piezo-potential or piezo-charges. The piezo-phototronic effect has demonstrated a promising way in enhancing the performances of various optoelectronic devices, such as photovoltaic cells, light-emitting diodes (LEDs), photodetectors, and spin devices.

In this work, the presence of a strong spin–orbit coupling (SOC) in the CsPbBr₃ QDs was confirmed. A strong piezoelectric property in CsPbBr₃ QDs was discovered and investigated after the QDs have undergone a cooling-treated process, which has a great influence on the spin–orbit coupled photoluminescence (PL). The piezo-phototronic effect was used to tune the spin–orbit coupled PL intensity with a simple application of bending strain on the QDs’ covered flexible substrate. These findings are of great significance to the development of advanced optoelectronic and spintronic devices.

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applications based on perovskite QDs with outstanding quantum confinement effects.

The CsPbBr$_3$ QDs' solution showed a light green color (Figure 1a) and was dropped on the surface of a flexible polyethylene terephthalate (PET) substrate with 500 μm in thickness for further applying strain on the QDs (Figure 1a, Figure S1 and Note S1, Supporting Information). Figure 1b illustrates the absorption and PL spectra of the CsPbBr$_3$ QDs at 300 K with an optical PL peak of 508 nm and a narrow full width at half-maximum (FWHM) of 17 nm. The diameter of the laser spot for all of the following measurements was 2 mm. The power density dependence of the normalized PL intensity is almost linear for both 508 and 538 nm wavelengths (Figure 1c and Figure S2, Supporting Information). The time-resolved

Figure 1. Characterization of the all-inorganic perovskite CsPbBr$_3$ QDs. (a) A schematic diagram of QDs on a substrate (i), an optical image of QDs on a glass substrate (ii), and an optical image of a 2 mm size dropped QDs on PET substrate (iii). (b) Absorption and PL spectra of the QDs. (c) Normalized PL intensity as a function of the power density of a 325 nm laser. (d) TRPL spectrum of the QDs corresponding to 508 nm. (e) XRD of the glass substrate and the QDs/glass. (f) HRTEM image of the CsPbBr$_3$ QDs along [001] zone axis (z-axis). The inset at the bottom right corner denotes the corresponding FFT image. (g) EDX spectrum of the CsPbBr$_3$ QDs.

Figure 2. Normalized PL spectra of the as-fabricated QDs under different strains. (a,b) Normalized PL spectra excited with LP (a) and CP (b) lights. (c) Normalized PL intensity corresponding to the emission wavelength of 538 nm as a function of strain. The upper left and bottom right insets in (c) sketch the compressive and tensile strains, respectively, along z-axis of the QDs.
PL (TRPL) spectrum reveals a fast recombination time of 6.8 ns on average (Figure 1d), indicating that the radiation of CsPbBr₃ QDs is mainly derived from exciton recombination. From the X-ray powder diffraction (XRD), only (002) and (004) indices of the crystal face were detected, which shows a uniform distribution of the CsPbBr₃ QDs with [001] or [001] direction. The slightly smaller PL intensity for CP light excitation compared with that of LP light excitation is believed to be derived from the presence of Rashba SOC, and the PL measured in this work will be refined as the spin–orbit coupled PL, whose detailed physical picture will be discussed later.

The temperature dependence of the normalized PL spectra of the CsPbBr₃ perovskite QDs on a p-Si substrate is displayed in Figure 3. The experimental setup is shown in the inset of Figure 3a. When decreasing temperature from 294 to 78 K, the peak intensity of PL spectra is increasing while the PL peak position appears as a reduced photon energy (i.e., a redshift) (Figure 3a). The redshift is opposite to that expected for typical semiconductors such as Si, Ge, and GaAs. The PL spectra are not strictly symmetrical around their peaks, which is believed to be due to the presence of free-exciton and bright tail states that allow different radiative recombinations of excitons localized in the states. A diagram of carrier recombination dynamics after electrons excited from the valence band (VB) to the conduction band (CB) is illustrated in Figure 3b. The redshift of the lower-energy peak corresponds to the enhanced recombination of carriers relaxed in the tail states with the decrease of temperature. The temperature dependence of PL peak positions (i.e., photon energies) and that of PL spectra FWHM is summarized in the blue and green labels in Figure 3c, respectively. The recombination luminescence from the bright tail states is becoming much more dominant than that from the free-exciton states with a further decrease of temperature from 200 K; as a result, the peak position shows a severe redshift below 200 K. The PL spectra FWHM shows a linear decrease with a slope of 0.037 nm/K as temperature is decreasing in the whole measured range. In comparison with traditional QDs based on Cd-chalcogenides and rare-earth phosphors, the perovskite QDs possess outstanding quantum efficiency and narrower FWHM of PL intensity spectra. Therefore, perovskite QDs can be synthesized for more saturated colors and hold better application potentials in QLED displays.

The more interesting phenomenon is that the perovskite CsPbBr₃ QDs demonstrated a piezoelectric property when they experienced a cooling treatment at 200 K for 20 min, and the piezoelectric property can be maintained even when the...
temperature has risen to 292 K (a controlled room temperature). Considering that the low-temperature resistance of the PET substrate is limited to around 200 K, the cooling temperature was thus selected to be 200 K to allow phase transition and not damage the PET substrate. The PL intensity also reveals a dependence on the polarization of the exciting laser light (532 nm). As shown in Figure 4a, the normalized intensity of spin–orbit coupled PL spectrum of the CsPbBr₃ perovskite QDs for both right circularly polarized (RCP) and left circularly polarized (LCP) light excitations are almost the same (Figure 4a red and blue lines, respectively) while slightly smaller than that for LP light excitation (Figure 4a black line). The downward bending of PL for the case of LP light on PET is due to the absorption of PET. Later, the strain dependences of the normalized intensity of the spin–orbit coupled PL spectrum for LP (Figure 4b) and CP (Figure 4c) light excitations were studied. Both investigations reveal PL intensity increases when applied compressive strain increases and decreases when applied tensile strain increases. The normalized spin–orbit coupled PL intensity as a function of strain corresponding to the emission wavelength of 538 nm is extracted in Figure 4d. Note that the manipulations of spin–orbit coupled PL intensity in the table of Figure 4d are amended in consideration of the modulation of PL due to the different light scatterings with the change of device geometry according to Figure 2c. For an LP light excitation, the normalized spin–orbit coupled PL intensity is enhanced by 136% and decreased by 57% under a −0.9% compressive strain and a 0.9% tensile strain, respectively. For a CP light excitation under the same compressive and tensile strain, the spin–orbit coupled PL intensity is enhanced by 146% and decreased by 53%. Compared to untreated QDs (Figure 2c), the PL intensity response to strains is quite different when QDs have undergone a cooling treatment (Figure 4d and Figure S4, Supporting Information). This is a strong demonstration of the piezo-phototronic effect tuned-photoluminescence based on CsPbBr₃ QDs. The effect should be attributed to the structural transformation of QDs from a cubic structure with a space group of $Pm\bar{3}m$ to an orthorhombic structure with a space group of $Pna2_1$ due to the cooling treatment, as illustrated in Figure 4e, and the $Pna2_1$ phase can be maintained even at 292 K. But a heating treatment at 310 K for 20 min can turn the $Pna2_1$ phase back to the cubic phase, as demonstrated in Figure S5 (see Supporting Information). The $Pna2_1$ group is a noncentrosymmetric structure, which results in the piezoelectricity of materials. Very recently, Li et al. proved that the ferroelectricity in cooling-treated perovskite CsPbBr₃ QDs is due to the distorted structure with twisting and tilting of the $[\text{PbBr}_6]^{4-}$ and the off-centered Cs⁺ causing a weak separation of centers of positive and negative charges, which were obtained by a polarization-electric field hysteresis loop measurement using a ferroelectric tester. The present work is more evidence of the presence of piezoelectric property for cooling-treated perovskite CsPbBr₃ QDs.

The possible mechanism accounting for the polarization dependence of the spin–orbit coupled PL is proposed. Regarding the CsPbBr₃ QD as a supermolecule, electrons (holes) will move around the supermolecule, whose spins will couple, identically as the single molecule case with the p-orbitals of the Pb (the s-orbital of the Pb and p-orbitals of the surrounding Br), resulting in spin-splittings in the CB and VB with the same spin states of $\frac{1}{2} [+\frac{1}{2}, -\frac{1}{2}]$, $\frac{1}{2} [+\frac{3}{2}, -\frac{1}{2}]$, $\frac{1}{2} [+\frac{3}{2}, -\frac{3}{2}]$ and $\frac{1}{2} [+\frac{1}{2}, -\frac{3}{2}]$. The stress-free case shows a spontaneous polarization $P_s$ with a moderate piezo-potential as CsPbBr₃ QDs uniformly oriented

![Figure 4. Normalized spin–orbit coupled PL of the CsPbBr₃ perovskite QDs after a cooling treatment. (a) Normalized PL spectra of the QDs and PET for different light polarizations. (b) Normalized PL spectra excited with LP light and under different strains. (c) Normalized PL spectra excited with CP light and under different strains. (d) Normalized PL intensity corresponding to the emission wavelength of 538 nm as a function of strain for LP and CP excitations. The inset table illustrates amended manipulations for LP and CP excitations under −0.9% and 0.9% strains. (e) Schematic transformation of phase structure after a cooling treatment of 200 K.](https://dx.doi.org/10.1021/acs.nanolett.0c03470)
along +z or −z axis on the PET substrate. Although the polarity directions of the QDs may be reversed, that is, along +z or −z, the variation tendencies of the piezo-potential are the same, that is, both increasing or both decreasing under the same strain. The piezo-potential decreases when QDs are compressed along the z-axis and increases when QDs are stretched, as illustrated in Figure 5a. An increase of piezo-potential can not only strengthen the Rashba SOC but also severely incline the spin-split band levels. When QDs are excited by an LP light with angular momentum of 0 and compressed with a weaker piezo-potential (i.e., applying a small compressive strain), photoinduced carriers are excited from the spin-split VB \( \left( \frac{1}{2}, \frac{1}{2} \right) \) to the spin-split CB \( \left( \frac{1}{2}, -\frac{1}{2} \right) \) (process 1 in Figure 5d) according to the optical transition selection rule. \(^{36}\) The excited spin-polarized electrons and holes will be drifted slightly under the weak piezo-potential (process 2 in Figure 5d) and also experience a spin-flipping to the opposite spin-subband levels nearby (process 3 in Figure 5d); finally a spin–orbit coupled PL intensity is measured due to the carrier recombination corresponding to processes 4, 5, and 6 in Figure 5d. The processes 3 and 4 may be much more dominant than the processes 5 and 6, thus a nearly direct recombination transition of process 4 will emit a large amount of LP light, which is the reason why PL intensity for a CP light excitation is only slightly reduced compared to that for an LP light excitation (Figure 4a). When a strong piezo-potential is emerged (i.e., a stretched case, see Figure 5e), the spin-split energy levels will be tilted more seriously, and hence the electron–hole pairs will be separated more seriously, which will suppress the recombination luminescence due to the stronger indirect bandgap property. In other words, for a CP light excitation an increased compressive strain will reduce the magnitude of piezo-potential and thus enhance PL intensity, while an increased tensile strain reduces PL intensity, as shown in Figure 4c,d. As they are more severe with indirect recombination for CP light excitation, in general the spin–orbit coupled PL intensity for CP light excitation is weaker compared with that for LP light excitation. Also, the cubic-structured CsPbBr\(_3\) QDs also reveal a Rashba SOC although it does not possess a piezoelectricity (Figure 2c). The PL spectra for RCP and LCP light excitations under the same piezo-potential are nearly the same (Figure 4a) which is probably because the spin-flipping process 3 and the subsequent recombination luminescence process 4 are dominant, whereas the recombination luminescence processes 5 and 6 are relatively weak.

In conclusion, the piezo-phototronic effect is shown to effectively tune the spin–orbit coupled PL intensity based on all-inorganic perovskite CsPbBr\(_3\) QDs. The QDs with a cooling treatment are demonstrated to yield a piezoelectric property and a spontaneous polarization, which can be maintained even after the temperature is raised to 292 K. The piezo-potential can tune not only the Rashba SOC but also the inclination of the spin-split band levels. For LP and CP light excitations, the normalized spin–orbit coupled PL intensities can be enhanced effectively by 136% and 146%, respectively. The spin–orbit coupled PL intensity for LP light excitation is larger than that for CP light excitation due to the different carrier recombination processes in the spin-split band levels. These findings demonstrate that the piezo-phototronic effect can still work at all-inorganic perovskite-based QDs, revealing great potential of advanced optoelectronic and spintronic applications of the piezo-phototronic effect in these QDs.
Photograph of PET substrate covered by a circular Kapton tape (Figure S1), normalized PL spectra under different light power (Figure S2), an enlarged view of the HRTEM image (Figure S3), a comparison of the normalized spin–orbit coupled PL intensity for different cooling treatments and light polarizations (Figure S4), normalized spin–orbit coupled PL spectra after a heating treatment (Figure S5), schematic experimental setup and optical path of the measurement (Figure S6), and several notes about experimental methods (Note S1), thickness statement (Note S2), strain calculation (Note S3), piezophototronic effect on PL spectrum and the heating effect on piezo-charges (Note S4) (PDF).

Author Contributions
L.Z. and Z.L.W. designed the experiments. L.Z. conducted the experiments. L.Z. and Z.L.W. wrote the manuscript. All coauthors read and commented on the manuscript.

Notes
The authors declare no competing financial interest.

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REFERENCES


